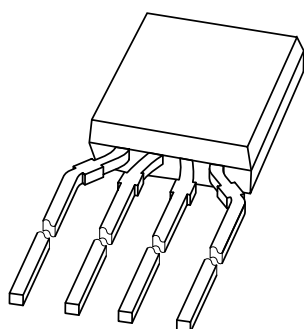


DATA SHEET



KMZ10B Magnetic field sensor

Product specification
Supersedes data of 1996 Nov 08
File under Discrete Semiconductors, SC17

1998 Mar 31

Magnetic field sensor

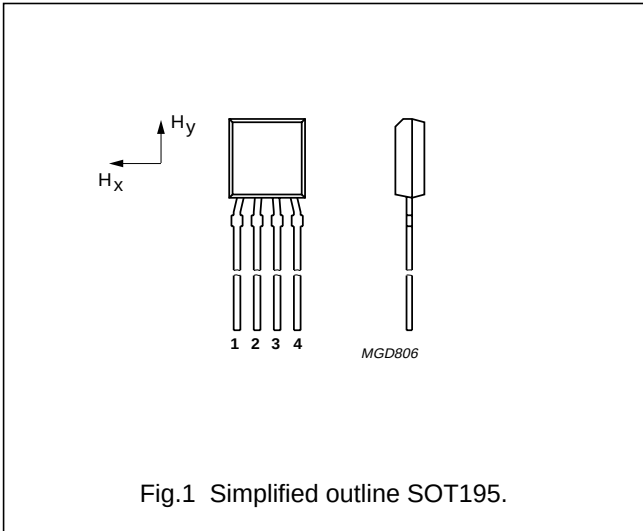
KMZ10B

DESCRIPTION

The KMZ10B is a sensitive magnetic field sensor, employing the magnetoresistive effect of thin-film permalloy. Its properties enable this sensor to be used in a wide range of applications for current and field measurement, revolution counters, angular or linear position measurement, proximity detectors, etc.

PINNING

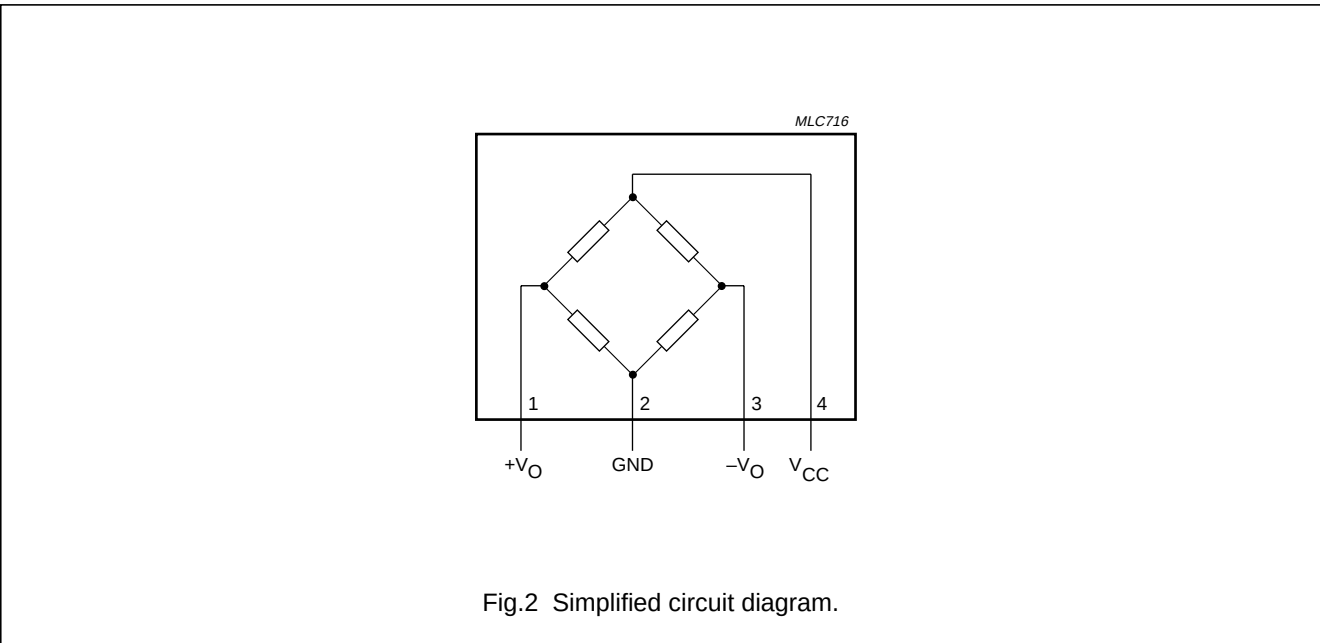
PIN	SYMBOL	DESCRIPTION
1	+V _O	output voltage
2	GND	ground
3	-V _O	output voltage
4	V _{CC}	supply voltage



QUICK REFERENCE DATA

SYMBOL	PARAMETER	MIN.	TYP.	MAX.	UNIT
V _{CC}	bridge supply voltage	–	5	12	V
H _y	magnetic field strength	–2	–	+2	kA/m
H _x	auxiliary field	–	3	–	kA/m
S	sensitivity	–	4	–	$\frac{mV/V}{kA/m}$
R _{bridge}	bridge resistance	1.6	–	2.6	kΩ
V _{offset}	offset voltage	–1.5	–	+1.5	mV/V

CIRCUIT DIAGRAM



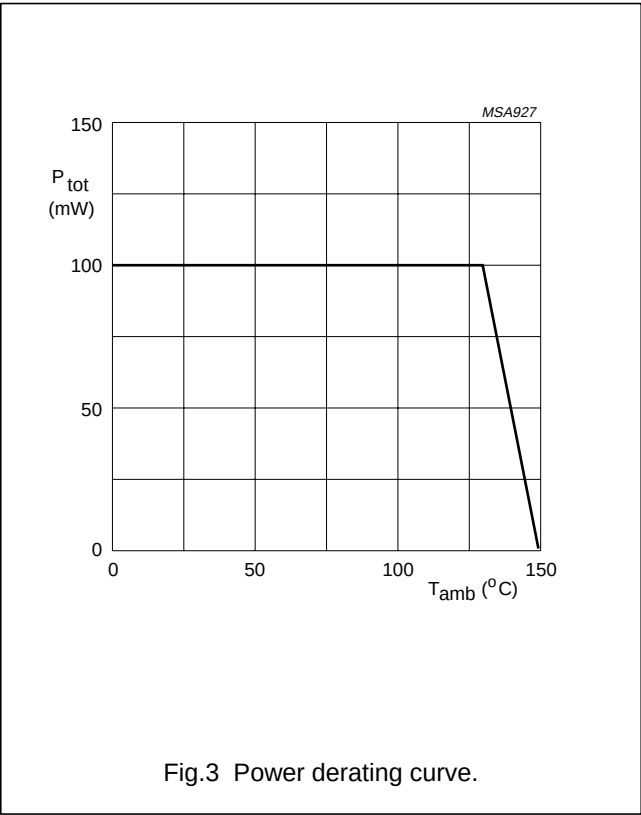
Magnetic field sensor

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LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CC}	bridge supply voltage		–	12	V
P _{tot}	total power dissipation	up to T _{amb} = 130 °C	–	120	mW
T _{stg}	storage temperature		–65	+150	°C
T _{bridge}	bridge operating temperature		–40	+150	°C



Magnetic field sensor

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THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	180	K/W

CHARACTERISTICS

$T_{amb} = 25\text{ °C}$; $H_x = 3\text{ kA/m}$; note 1.

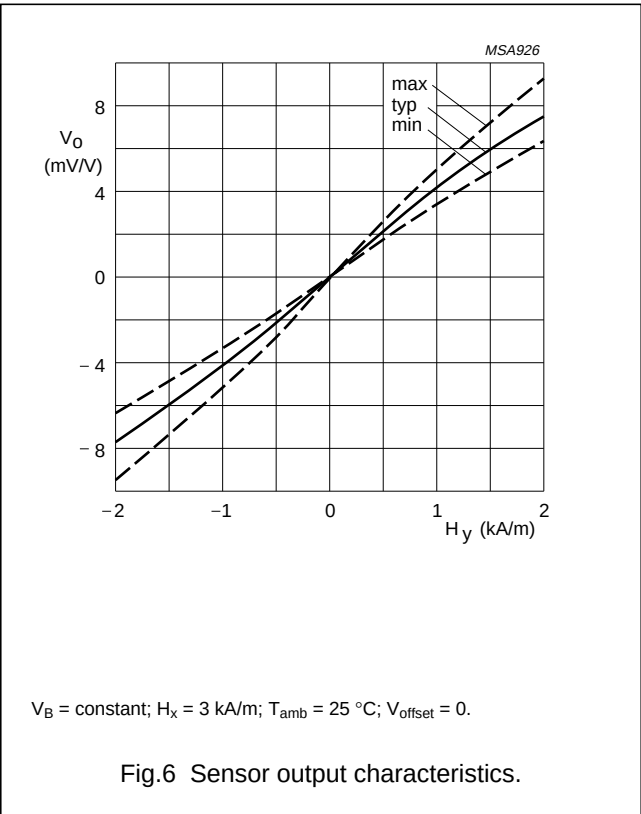
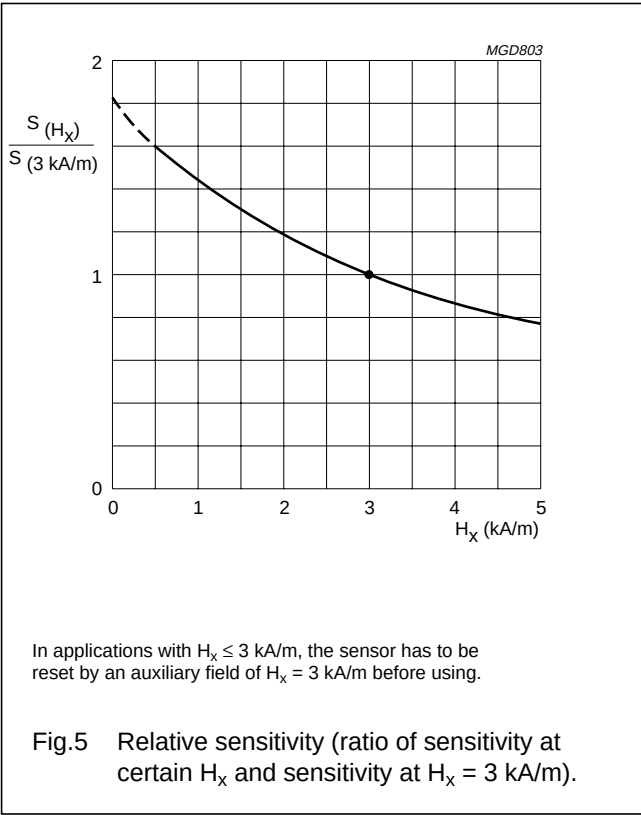
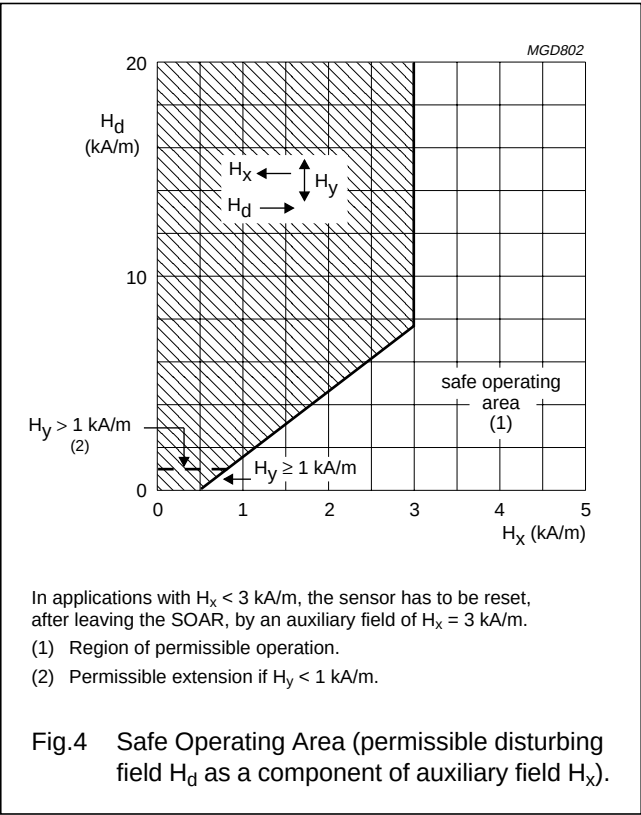
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{CC}	bridge supply voltage		–	5	–	V
H_y	magnetic field strength		–2	–	+2	kA/m
S	sensitivity	open circuit, notes 2 and 3	3.2	–	4.8	$\frac{mV/V}{kA/m}$
TCV_O	temperature coefficient of output voltage	$V_{CC} = 5\text{ V}$; $T_j = -25\text{ to }+125\text{ °C}$	–	–0.4	–	%/K
		$I_B = 3\text{ mA}$; $T_j = -25\text{ to }+125\text{ °C}$	–	–0.1	–	%/K
R_{bridge}	bridge resistance		1.6	–	2.6	k Ω
TCR_{bridge}	temperature coefficient of bridge resistance	$T_{bridge} = -25\text{ to }+125\text{ °C}$	–	0.3	–	%/K
V_{offset}	offset voltage		–1.5	–	+1.5	mV/V
TCV_{offset}	offset voltage drift	$T_j = -25\text{ to }+125\text{ °C}$	–3	–	+3	$\frac{\mu V/V}{K}$
FL	linearity deviation of output voltage	$H_y = 0\text{ to } \pm 1\text{ kA/m}$	–	–	± 0.5	%-FS
		$H_y = 0\text{ to } \pm 1.6\text{ kA/m}$	–	–	± 1.7	%-FS
		$H_y = 0\text{ to } \pm 2\text{ kA/m}$	–	–	± 2	%-FS
FH	hysteresis of output voltage		–	–	0.5	%-FS
f	operating frequency		0	–	1	MHz

Notes

- In applications with $H_x < 3\text{ kA/m}$ the sensor has to be reset before first operation by application of an auxiliary field $H_x = 3\text{ kA/m}$.
- No disturbing field (H_d) allowed; for stable operation under disturbing conditions see Fig.4 (SOAR) and see Fig.5 for decrease of sensitivity.
- $$S = \frac{(V_O \text{ at } H_y = 1.6\text{ kA/m}) - (V_O \text{ at } H_y = 0)}{1.6 \times V_{CC}} .$$

Magnetic field sensor

KMZ10B



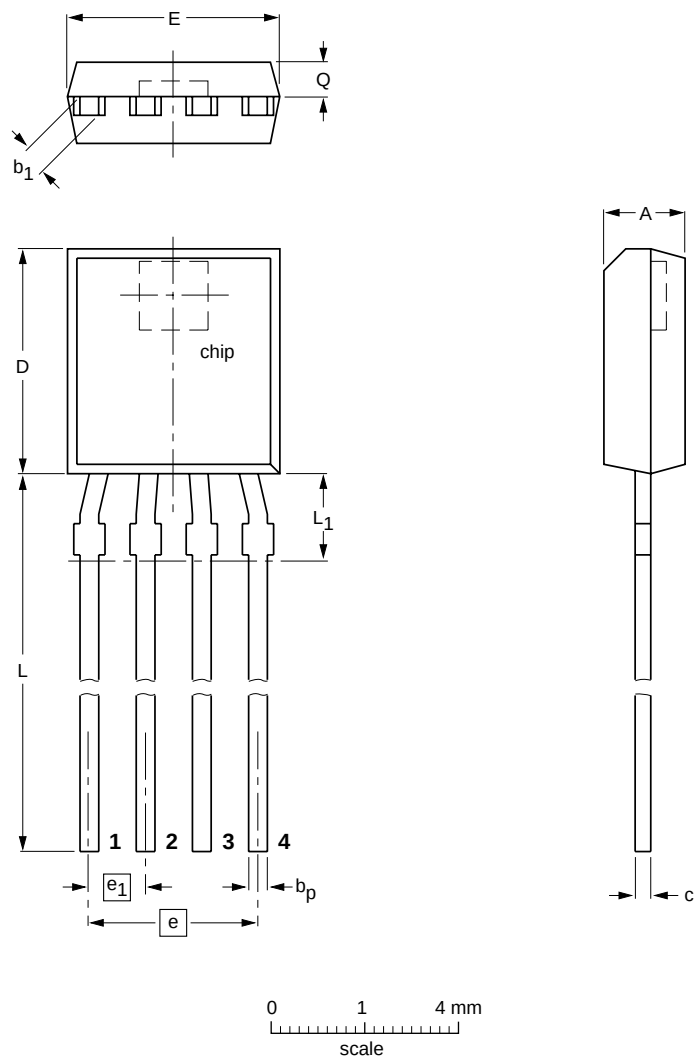
Magnetic field sensor

KMZ10B

PACKAGE OUTLINE

Plastic single-ended flat package; 4 in-line leads

SOT195

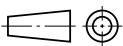


DIMENSIONS (mm are the original dimensions)

UNIT	A	b _p	b ₁	c	D	E	e	e ₁	L	L ₁ ⁽¹⁾ max.	Q
mm	1.8 1.6	0.48 0.40	0.7 0.5	0.45 0.39	5.2 5.0	4.8 4.4	3.75	1.25	14.5 12.7	2	0.8 0.7

Notes

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT195						97-06-02

Magnetic field sensor

KMZ10B

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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